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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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MOS FIELD EFFECT TRANSISTOR NP180N04TUG

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP180N04TUG is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP180N04TUG-E1-AY Note		Tape	TO-263-7pin (MP-25ZT)
NP180N04TUG-E2-AY Note	Pure Sn (Tin)	800 p/reel	typ. 1.5 g

Note Pb-free (This product does not contain Pb in the external electrode).

FEATURES

• Super low on-state resistance

 $R_{DS(on)}$ = 1.2 m Ω TYP. / 1.5 m Ω MAX. (Vgs = 10 V, ID = 90 A)

High Current Rating

 $I_{D(DC)} = \pm 180 A$

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGS = 0 V)	VDSS	40	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±180	Α
Drain Current (pulse) Note1	ID(pulse)	±720	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	288	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.8	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to +175	°C
Single Avalanche Energy Note2	Eas	518	mJ
Repetitive Avalanche Current Note3	lar	72	Α
Repetitive Avalanche Energy Note3	Ear	518	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 20 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H

3. Rg = 25 Ω , Tch(peak) $\leq 150^{\circ}$ C

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	0.52	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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(TO-263-7pin)

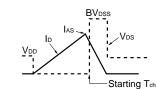


ELECTRICAL CHARACTERISTICS (TA = 25°C)

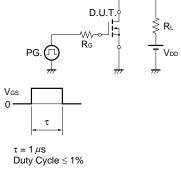
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 40 V, V _{GS} = 0 V			1	μА
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	2.0	3.0	4.0	V
Forward Transfer Admittance Note	y fs	V _{DS} = 5 V, I _D = 45 A	51	107		S
Drain to Source On-state Resistance Note	R _{DS(on)}	V _{GS} = 10 V, I _D = 90 A		1.2	1.5	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V,		17100	25700	pF
Output Capacitance	Coss	V _{GS} = 0 V,		1420	2130	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		890	1610	pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 20 V, I _D = 90 A,		54	120	ns
Rise Time	tr	V _{GS} = 10 V,		43	110	ns
Turn-off Delay Time	t _{d(off)}	R _G = 0 Ω		104	210	ns
Fall Time	tf			21	60	ns
Total Gate Charge	Q _G	V _{DD} = 32 V,		260	390	nC
Gate to Source Charge	QGS	V _{GS} = 10 V,		52		nC
Gate to Drain Charge	Q GD	I _D = 180 A		88		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 180 A, V _{GS} = 0 V		0.9	1.5	V
Reverse Recovery Time	trr	I _F = 180 A, V _{GS} = 0 V,		65		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>μ</i> s		110		nC

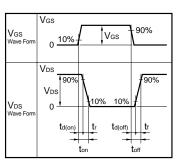
Note Pulsed test

TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME





TEST CIRCUIT 3 GATE CHARGE

$$\begin{array}{c|c}
D.U.T. & \\
IG = 2 \text{ mA} & \\
\hline
PG. & \\
\end{array}$$

$$\begin{array}{c|c}
PG. & \\
\end{array}$$

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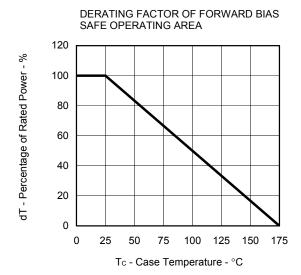
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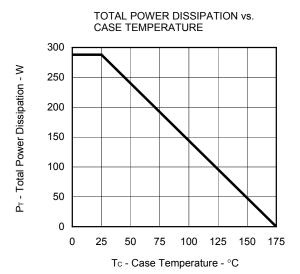
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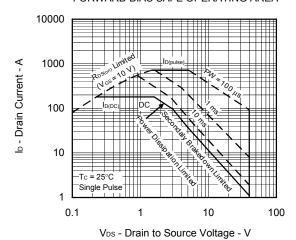
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TYPICAL CHARACTERISTICS (TA = 25°C)

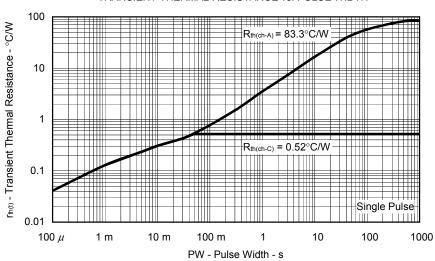




FORWARD BIAS SAFE OPERATING AREA



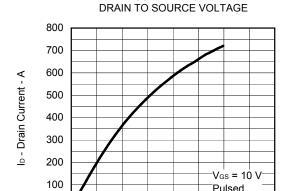
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



3

0

0



0.5

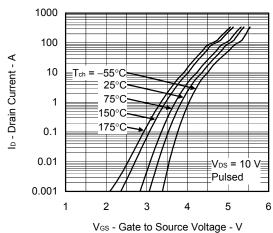
DRAIN CURRENT vs.

1 VDS - Drain to Source Voltage - V

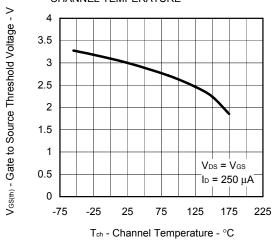
1.5

2

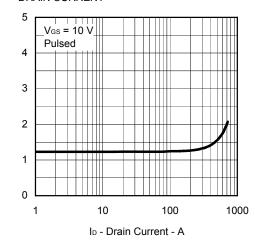
FORWARD TRANSFER CHARACTERISTICS



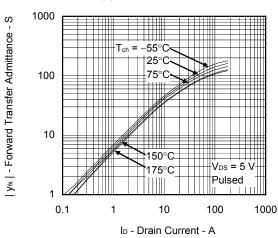
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



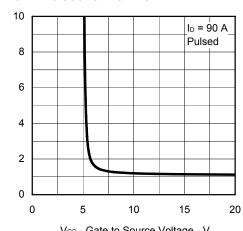
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



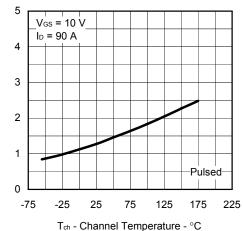
V_{GS} - Gate to Source Voltage - V

 $R_{DS(on)}$ - Drain to Source On-state Resistance - $m\Omega$

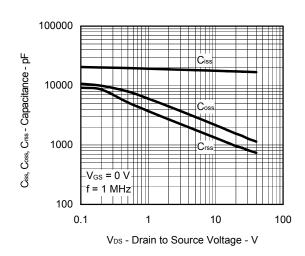
RDS(on) - Drain to Source On-state Resistance - mΩ

R_{DS(on)} - Drain to Source On-state Resistance - mΩ

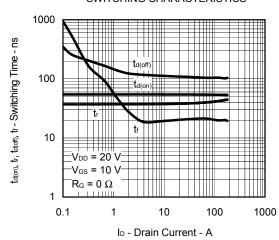




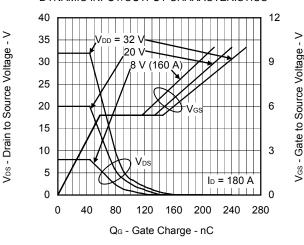
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



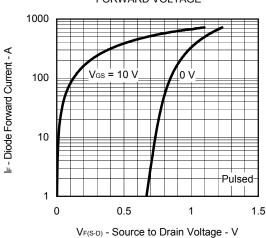
SWITCHING CHARACTERISTICS



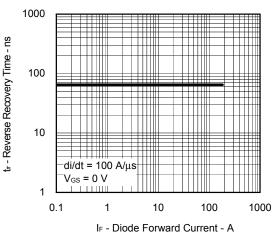
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



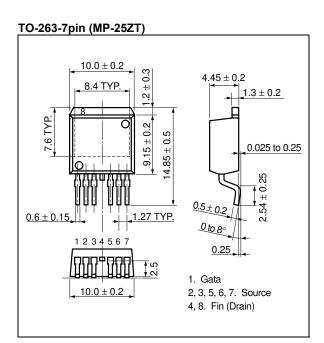
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



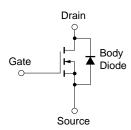
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT

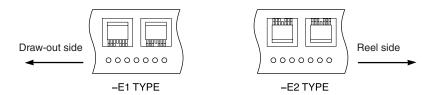


Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

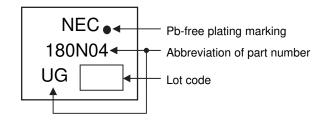
6

TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

The NP180N04TUG should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol	
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below		
	Time at maximum temperature: 10 seconds or less		
	Time of temperature higher than 220°C: 60 seconds or less	IR60-00-3	
	Preheating time at 160 to 180°C: 60 to 120 seconds		
	Maximum number of reflow processes: 3 times		
	Maximum chlorine content of rosin flux (percentage mass): 0.2% or less		
Partial heating	Maximum temperature (Pin temperature): 350°C or below		
	Time (per side of the device): 3 seconds or less	P350	
	Maximum chlorine content of rosin flux: 0.2% (wt.) or less		

Caution Do not use different soldering methods together (except for partial heating).

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